NSN 5961-01-029-1023

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-1023 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.092 inches and 0.104 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 6.7 breakdown voltage, collector to emitter, with specified voltage between base and emitter **Current Rating Per Characteristic:** 1.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Test Data Document:** 10001-2889767 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No